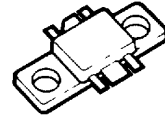


**MOTOROLA**  
**SEMICONDUCTOR**  
**TECHNICAL DATA**
**Advance Information**
**The RF Line**
**UHF Power Transistor**

... designed for common-emitter operation in the 900 MHz mobile radio band. Use of gold metallization and silicon diffused ballast resistors results in a medium power output/driver transistor with state-of-the-art ruggedness and reliability.

- 960 MHz
- 15 W —  $P_{out}$
- 26 V —  $V_{CC}$
- High Gain — 8.5 dB, Class AB

**TP3022A**
**15 W — 960 MHz**  
**UHF POWER**  
**TRANSISTOR**  
**NPN SILICON**
**2**

**CASE 319-06, STYLE 2**  
**(EB)**
**MAXIMUM RATINGS**

| Rating                         | Symbol    | Value       | Unit |
|--------------------------------|-----------|-------------|------|
| Emitter-Base Voltage           | $V_{EBO}$ | 4           | Vdc  |
| Operating Junction Temperature | $T_J$     | 200         | °C   |
| Storage Temperature Range      | $T_{stg}$ | -65 to +200 | °C   |

**THERMAL CHARACTERISTICS**

| Characteristic  | Symbol          | Max | Unit |
|---|-----------------|-----|------|
| Thermal Resistance, Junction to Case ( $T_C = 70^\circ\text{C}$ ) | $R_{\theta JC}$ | 6   | °C/W |

**ELECTRICAL CHARACTERISTICS** ( $T_C = 25^\circ\text{C}$  unless otherwise noted)

| Characteristic | Symbol | Min | Typ | Max | Unit |
|----------------|--------|-----|-----|-----|------|
|----------------|--------|-----|-----|-----|------|

**OFF CHARACTERISTICS (Note 1)**

|  |                |    |   |   |     |
|--|----------------|----|---|---|-----|
| Collector-Emitter Breakdown Voltage ( $I_C = 10\text{ mA}$ , $R_{BE} = 75\text{ Ohms}$ ) | $V_{(BR)ICER}$ | 40 | — | — | Vdc |
| Collector-Emitter Leakage ( $V_{CE} = 26\text{ V}$ , $R_{BE} = 75\text{ Ohms}$ )         | $I_{CER}$      | —  | — | 5 | mA  |
| Emitter-Base Breakdown Voltage ( $I_C = 5\text{ mAdc}$ )                                 | $V_{(BR)EBO}$  | 4  | — | — | Vdc |
| Emitter-Base Leakage ( $V_{BE} = 2.5\text{ V}$ )   | $I_{EBO}$      | —  | — | 1 | mA  |

**ON CHARACTERISTICS**

|  |          |    |   |     |   |
|--|----------|----|---|-----|---|
| DC Current Gain ( $I_C = 500\text{ mA}$ , $V_{CE} = 10\text{ V}$ ) | $h_{FE}$ | 15 | — | 100 | — |
|--|----------|----|---|-----|---|

**DYNAMIC CHARACTERISTICS**

|  |          |   |    |    |    |
|--|----------|---|----|----|----|
| Output Capacitance ( $V_{CB} = 24\text{ V}$ , $I_E = 0$ , $f = 1\text{ MHz}$ ) | $C_{ob}$ | — | 17 | 25 | pF |
|--|----------|---|----|----|----|

**FUNCTIONAL TESTS**

|   |          |     |   |   |    |
|---|----------|-----|---|---|----|
| Common-Emitter Amplifier Power Gain<br>( $V_{CE} = 26\text{ V}$ , $P_{out} = 15\text{ W}$ , $f = 960\text{ MHz}$ , $I_Q = 50\text{ mA}$ ) | $G_{PE}$ | 8.5 | — | — | dB |
| Collector Efficiency<br>( $V_{CE} = 26\text{ V}$ , $P_{out} = 15\text{ W}$ , $f = 960\text{ MHz}$ , $I_Q = 50\text{ mA}$ )                | $\eta_c$ | 45  | — | — | %  |

This document contains information on a new product. Specifications and information herein are subject to change without notice.

**MOTOROLA RF DEVICE DATA**
**2-1193**